LE B P3MQ

OSRAM OSTAR® Projection Power

OSRAM OSTAR Projection Power is a high luminance LED for projection applications.



Applications

- Projection Home LED & Laser

- Projection Professional LED & Laser

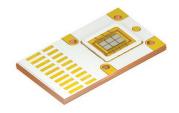
Features:

- Package: OSTAR High Power Projection
- Chip technology: UX:3
- Typ. Radiation: 120° (Lambertian emitter)
- Color: λ_{dom} = 456 nm (• blue)
- ESD: 2 kV acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)

Ordering Information

Туре	Total radiant flux ¹⁾ Ι _F = 6000 mA Φ _e	Ordering Code
LE B P3MQ-HRJP-23	33000 48400 mW	Q65112A7817





Maximum Ratings

min.	-40 °C
max.	85 °C
max.	150 °C
min.	200 mA
max.	10000 mA
	12000 mA
max.	14000 mA
	2 kV
max.	200 mA
max.	40 V
-	max.

OS-IN-2021-008-A



Characteristics

 $\rm T_{Board}$ = 25 °C; $\rm I_{F}$ = 6000 mA; f = 1000 Hz; D = 0.25

Parameter	Symbol		Values	
Peak Wavelength	λ_{peak}	typ.	450 nm	
Dominant Wavelength 3)	λ _{dom}	min.	452 nm	
		typ.	456 nm	
		max.	460 nm	
Spectral bandwidth at 50% I _{rel,max}	$ riangle\lambda$	typ.	23 nm	
Viewing angle at 50% ${\rm I_v}$	2φ	typ.	120 °	
Radiating surface	A _{color}	typ.	4.85 x 2.60	
	00.01		mm²	
Partial Flux acc. CIE 127:2007 4)	Φ _{E/V, 120°}	typ.	0.77	
I _F = 6000 mA				
Forward Voltage ⁵⁾	V _F	min.	19.2 V	
I _F = 6000 mA		typ.	21.0 V	
		max.	22.8 V	
Reverse voltage (ESD device)	V _{r esd}	min.	45 V	
Reverse voltage 2)	V _R	max.	1.2 V	
I _R = 20 mA				
Real thermal resistance junction/board	$R_{thJB real}$	typ.	0.45 K / W	
Electrical thermal resistance junction/board	R _{thJB elec.}	typ.	0.31 K / W	
with efficiency η_e = 31 %				

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Brightness Groups

Group	Total radiant flux ¹⁾ I _F = 6000 mA min. Φ _e	Total radiant flux ¹⁾ $I_F = 6000 \text{ mA}$ max. Φ_e
HR	33000 mW	35900 mW
HS	35900 mW	39000 mW
HT	39000 mW	41900 mW
HU	41900 mW	45000 mW
JP	45000 mW	48400 mW

Wavelength Groups

Group	Dominant Wavelength 3)	Dominant Wavelength ³⁾
	min.	max.
	λ_{dom}	λ_{dom}
2	452 nm	456 nm
3	456 nm	460 nm

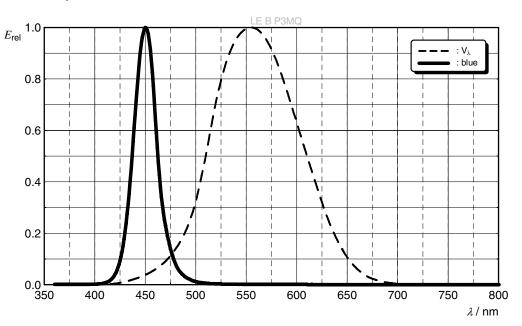
Group Name on Label

Example: HR-2	
Brightness	Wavelength
HR	2



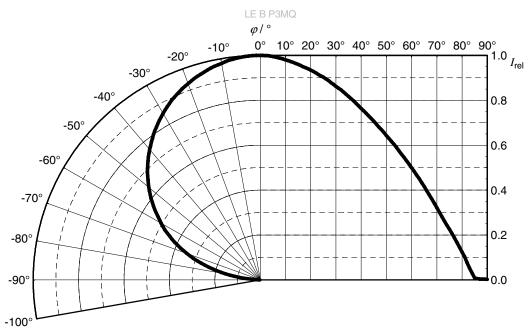
Relative Spectral Emission⁴⁾

 $E_{rel} = f(\lambda); I_{F} = 6000 \text{ mA}; T_{J} = 25 \text{ }^{\circ}\text{C}$



Radiation Characteristics⁴⁾

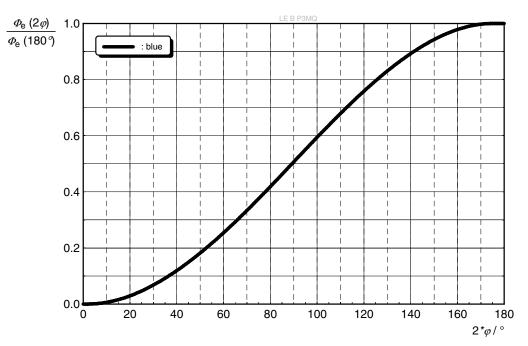
 $I_{rel} = f(\phi); T_J = 25 \ ^{\circ}C$





Relative Partial Flux⁴⁾

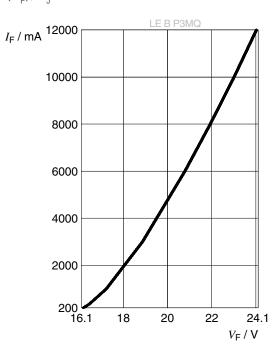
 $\Phi_{_{\rm E}}(2\phi)/\Phi_{_{\rm E}}(180^\circ) = f(\phi); T_{_{\rm J}} = 25 \ ^{\circ}{\rm C}$





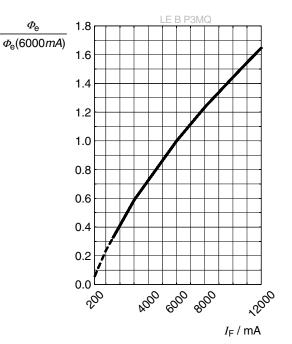
Forward current ⁴⁾

 $I_F = f(V_F); T_J = 25 \ ^{\circ}C$



Relative Radiant Power 4), 6)

 $\Phi_{E}/\Phi_{E}(6000 \text{ mA}) = f(I_{F}); T_{J} = 25 \text{ °C}$

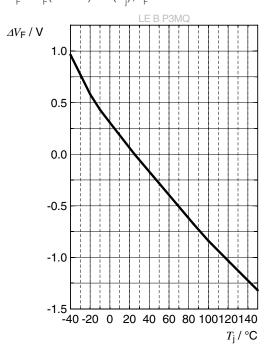


Dominant Wavelength ⁴⁾

 $\Delta \lambda_{dom} = f(I_F); T_J = 25 °C$

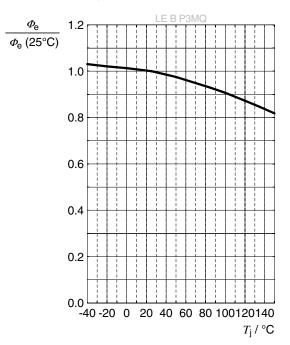


Forward Voltage ⁴⁾ $\Delta V_F = V_F - V_F (25 \ ^{\circ}C) = f(T_j); I_F = 6000 \text{ mA}$



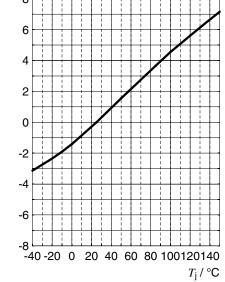
Relative Radiant Power⁴⁾

 $\Phi_{E}/\Phi_{E}(25 \text{ °C}) = f(T_{i}); I_{E} = 6000 \text{ mA}$



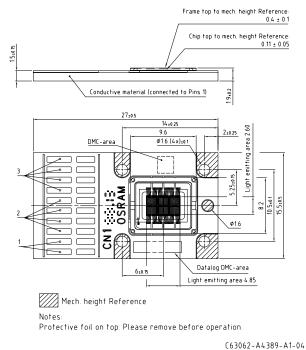
Dominant Wavelength ⁴⁾

 $\Delta \lambda_{dom} = \lambda_{dom} - \lambda_{dom} (25 \text{ °C}) = f(T_j); I_F = 6000 \text{ mA}$ $\Delta \lambda_{dom} / \text{ nm} \begin{array}{c} 10 \\ 8 \\ 6 \\ 4 \\ 2 \end{array}$





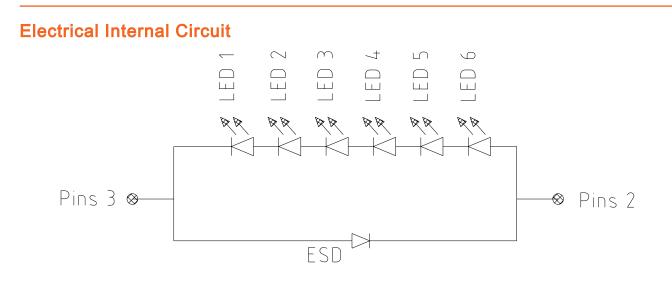
Dimensional Drawing 7)



Further Information:

Approximate Weight:	5,000.0 mg
ESD advice:	The device is protected by ESD device which is connected in parallel to the Chip.
Notes:	Package not suitable for any kind of wet cleaning or ultrasonic cleaning.
Connector:	Molex Pico-SPOX™ Wire-to-Board Header, Part Number 87438-1043
Recommended mating connector:	Molex Pico-SPOX™ Wire-to-Board Housing, Part Number 87439-1000 Crimp Terminal, Part Number 87421-0000



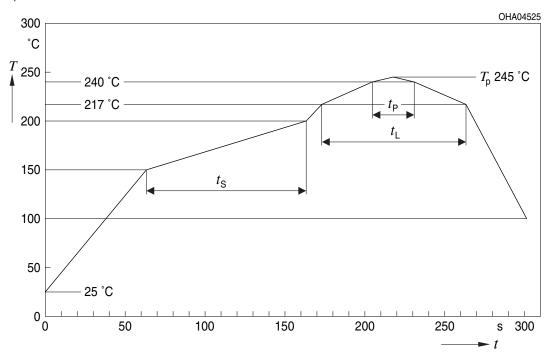


Pins 1: Substrate potential, isolated from Cathode and Anode Pins 2: Anode Pins 3: Cathode



Reflow Soldering Profile

Product complies to MSL Level 2 acc. to JEDEC J-STD-020E



Profile Feature	Symbol Pb-Free (SnAg		-Free (SnAgCu) Ass	embly	Unit
		Minimum	Recommendation	Maximum	
Ramp-up rate to preheat ^{•)} 25 °C to 150 °C			2	3	K/s
Time t _s T _{smin} to T _{smax}	t _s	60	100	120	S
Ramp-up rate to peak ^{*)} T_{smax} to T_{p}			2	3	K/s
Liquidus temperature	TL		217		°C
Time above liquidus temperature	t		80	100	S
Peak temperature	T _P		245	260	°C
Time within 5 °C of the specified peak temperature T_p - 5 K	t _P	10	20	30	S
Ramp-down rate* T _P to 100 °C			3	6	K/s
Time 25 °C to T _P				480	S

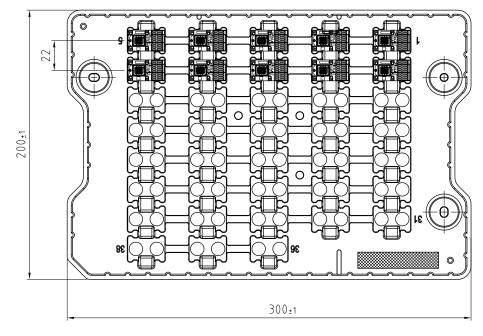
All temperatures refer to the center of the package, measured on the top of the component

* slope calculation DT/Dt: Dt max. 5 s; fulfillment for the whole T-range



Tray 7)

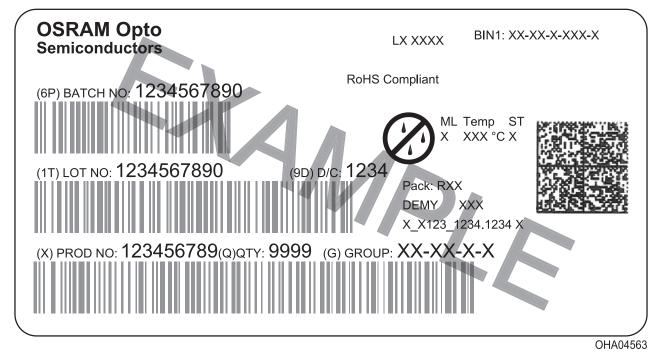
38 pieces per Tray



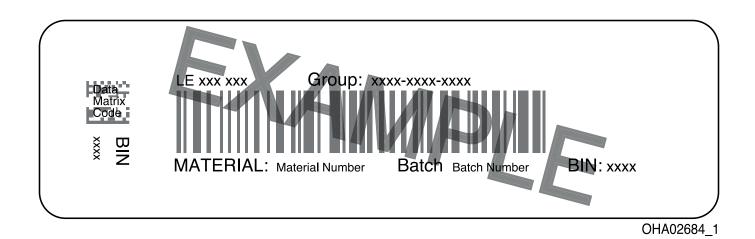
C63062-A4389-B10-01



Barcode-Product-Label (BPL)

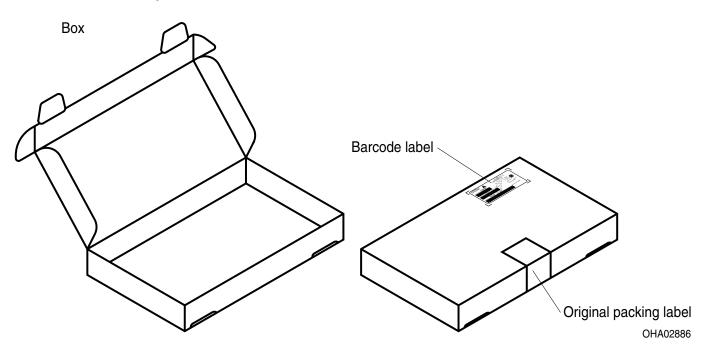


Barcode-Tray-Label (BTL)





Schematic Transportation Box 7)



Dimensions of Transportation Box

Width	Length	Height	
333 ± 5 mm	218 ±5 mm	28 ± 5 mm	
337 ± 5 mm	218 ±5 mm	63 ± 5 mm	

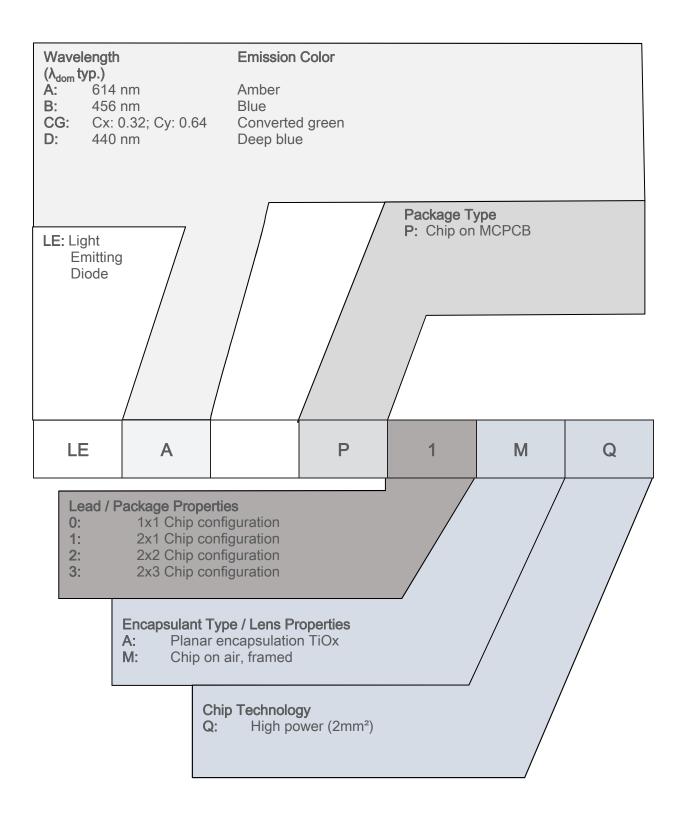


Data Matrix Code Description

The Data Matrix Code bin information is Laser marked during testing Content: aaaa@bbbbb@cccc@ddddd@eeeee Data Matrix Code Type: ECC200

a = Luminous Flux (Phiv) [Im] or Radiant Flux (Phie) [W]	(example: 3306)
b = Forward Voltage (Vf) [V]	(example: 3.46)
c = Wavelength (Ldom) [nm]	(example: 618)
d = Color Coordinate Cx	(example: 0.321)
e = Color Coordinate Cy	(example: 0.641)
@: Seperator = Blank	

Type Designation System





Notes

The evaluation of eye safety occurs according to the standard IEC 62471:2006 (photo biological safety of lamps and lamp systems). Within the risk grouping system of this IEC standard, the device specified in this data sheet fall into the class **moderate risk (exposure time 0.25 s)**. Under real circumstances (for exposure time, conditions of the eye pupils, observation distance), it is assumed that no endangerment to the eye exists from these devices. As a matter of principle, however, it should be mentioned that intense light sources have a high secondary exposure potential due to their blinding effect. When looking at bright light sources (e.g. headlights), temporary reduction in visual acuity and afterimages can occur, leading to irritation, annoyance, visual impairment, and even accidents, depending on the situation.

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

For further application related information please visit www.osram-os.com/appnotes



Disclaimer

Attention please!

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version on the OSRAM OS website.

Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

Product and functional safety devices/applications or medical devices/applications

OSRAM OS components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

OSRAM OS products are not qualified at module and system level for such application.

In case buyer – or customer supplied by buyer – considers using OSRAM OS components in product safety devices/applications or medical devices/applications, buyer and/or customer has to inform the local sales partner of OSRAM OS immediately and OSRAM OS and buyer and /or customer will analyze and coordinate the customer-specific request between OSRAM OS and buyer and/or customer.



Glossary

- ¹⁾ Brightness: Brightness values are measured during a pulse train of 100 ms with a pulse width of 250 µs and a frequencey of 1 kHz, with an internal reproducibility of +/- 8 % and an expanded uncertainty of +/- 11 % (acc. to GUM with a coverage factor of k = 3). The peak brightness is calculated according to the pulse duration and frequency.
- ²⁾ Reverse Operation: This product is intended to be operated applying a forward current within the specified range. Applying any continuous reverse bias or forward bias below the voltage range of light emission shall be avoided because it may cause migration which can change the electro-optical characteristics or damage the LED.
- ³⁾ **Wavelength:** The wavelength is measured during a pulse train of 100 ms with a pulse width of 250 μ s and a frequencey of 1 kHz, with an internal reproducibility of ± 0,5 nm and an expanded uncertainty of ± 1 nm (acc. to GUM with a coverage factor of k=3).
- ⁴⁾ Typical Values: Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- ⁵⁾ **Forward Voltage:** The forward voltage is measured during a pulse of typical 250 μs, with an internal reproducibility of +/- 0,05 V and an expanded uncertainty of +/- 0,1 V (acc. to GUM with a coverage factor of k=3).
- ⁶⁾ **Characteristic curve:** In the range where the line of the graph is broken, you must expect higher differences between single devices within one packing unit.
- ⁷⁾ **Tolerance of Measure:** Unless otherwise noted in drawing, tolerances are specified with ±0.1 and dimensions are specified in mm.



Revisior	Revision History		
Version	Date	Change	
1.0	2019-09-18	Glossary	
1.1	2020-02-18	Maximum Ratings Characteristics	
1.1	2020-02-18	Maximum Ratings Characteristics	
1.2	2020-07-21	Characteristics	
1.3	2021-03-19	Characteristics Maximum Ratings Ordering Information Brightness Groups Dimensional Drawing	



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